

# X006 Series 0.8A SCRs SENSITIVE

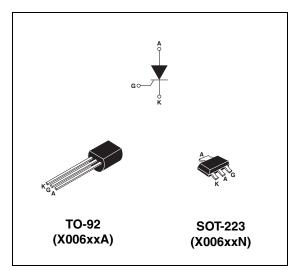
## **Main features**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	0.8	А
V <sub>DRM</sub> /V <sub>RRM</sub>	600	V
I <sub>GT</sub>	60 to 200	μA

## Description

Thanks to highly sensitive triggering levels, the **X006** SCR series is suitable for all applications where the available gate current is limited, such as ground fault circuit interrupters, overvoltage crowbar protection in low power supplies, capacitive ignition circuits, ...

Available in though-hole or surface-mount packages, these devices are optimized in forward voltage drop and inrush current capabilities, for reduced power losses and high reliability in harsh environments.



### Order codes

Part Numbers	Marking
X00602MA 1AA2	X0602 MA
X00602MA 2AL2	X0602 MA
X00602MA 5AL2	X0602 MA
X00602MN5BA4	X06 2M
X00605MA 1AA2	X0605 MA

# 1 Characteristics

Symbol	Parameter	Value	Unit			
I	DMS on state surrant (190° conduction angle)	TO-92	$T_I = 85^\circ C$	0.8	А	
I <sub>T(RMS)</sub> R	RMS on-state current (180° conduction angle) SO		$T_{tab} = 100^{\circ} C$	0.8	A	
IT			$T_I = 85^\circ C$	0.5	А	
IT <sub>(AV)</sub> A	Average on-state current (180° conduction angle)	SOT-223	$T_{tab} = 100^{\circ} C$	0.5	A	
<b>I</b>	Non repetitive surge peak on-state current	$t_{p} = 8.3 \text{ ms}$	- T <sub>i</sub> = 25° C	10	А	
I <sub>TSM</sub> N	Non repetitive surge peak on-state current	t <sub>p</sub> = 10 ms	1 <sub>j</sub> = 25 0	9	~	
l²t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms	$T_j = 25^\circ C$	0.4	A <sup>2</sup> s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100$ ns	F = 60 Hz	T <sub>j</sub> = 125° C	50	A/µs	
I <sub>GM</sub>	Peak gate current	t <sub>p</sub> = 20 μs	T <sub>j</sub> = 125° C	1	А	
P <sub>G(AV)</sub>	Average gate power dissipation		T <sub>j</sub> = 125° C	0.1	W	
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range	- 40 to + 150 - 40 to + 125	°C			

## Table 1. Absolute ratings (limiting values)

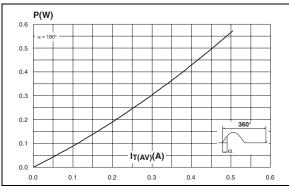
## Table 2. Electrical characteristics

Symbol	Test Conditions		X00602	X00605	Unit	
			MIN.	15	30	
I <sub>GT</sub>	$V_D = 12 V$ $R_L = 140 \Omega$		MAX.	200	60	μA
V <sub>GT</sub>			MAX.	0	.8	V
V <sub>GD</sub>	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $R_{GK} = 1 \text{ k}\Omega$	MIN.	0	.2	V	
V <sub>RG</sub>	Ι <sub>RG</sub> = 10 μΑ		MIN.	5		V
Ι <sub>Η</sub>	$I_T = 50 \text{ mA}$ $R_{GK} = 1 \text{ k}\Omega$	MAX.	5		mA	
١L	$I_G = 1 \text{ mA}$ $R_{GK} = 1 \text{ k}\Omega$		MAX.	6		mA
dV/dt	$V_D = 67\% V_{DRM}$ $R_{GK} = 1 k\Omega$	T <sub>j</sub> = 125° C	MIN.	2	5	V/µs
V <sub>TM</sub>	$I_{TM} = 1 \text{ A} \text{ tp} = 380 \ \mu \text{s}$ $T_j = 25^{\circ} \text{ C}$		MAX.	1.3	35	V
V <sub>t0</sub>	Threshold voltage $T_j = 125^{\circ}$		MAX.	0.8	85	V
R <sub>d</sub>	Dynamic resistance $T_j = 125^{\circ} C$ MAX.245				mΩ	
I <sub>DRM</sub>		T <sub>j</sub> = 25° C	MAX.	-	1	
I <sub>RRM</sub>	$V_{DRM} = V_{RRM}$ $R_{GK} = 1 k\Omega$	T <sub>j</sub> = 125° C	MAX.	10	00	μA

### Table 3.Thermal resistances

Symbol	Param	Value	Unit		
D lumption to ombient (D.C.)			TO-92	150	
R <sub>th(j-a)</sub> Junc	Junction to ambient (D.C.)	$S = 5 \text{ cm}^2$	SOT-223	60	°C/W
R <sub>th(j-l)</sub>	Junction to lead (D.C.)		TO-92	70	C/W
R <sub>th(j-t)</sub>	Junction to tab (DC)		SOT-223	30	1

# Figure 1. Maximum average power Figure 2. dissipation versus average on-state current



Average and D.C. on-state current versus case temperature (TO-92)

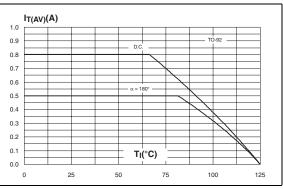
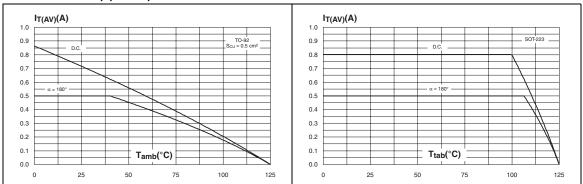


Figure 3. Average and D.C. on-state current Figure 4. versus ambient temperature (epoxy printed circuit board FR4, copper thickness  $e_{CU}$ =35 µm,  $S_{CU}$ = 0.5 cm<sup>2</sup>) (TO-92)

Average and D.C. on-state current versus casetemperature (SOT-223)





- Figure 5. Average and D.C. on-state current Figure 6. versus ambient temperature (epoxy printed circuit board FR4, copper thickness e<sub>CU</sub>=35 μm, S<sub>CU</sub>=5 cm<sup>2</sup>) (SOT-223)
- Relative variation of thermal impedance junction to ambient versus pulse duration (printed circuit board FR4, e<sub>CU</sub>=35 μm, S<sub>CU</sub>=0.5 cm<sup>2</sup>) (TO-92)

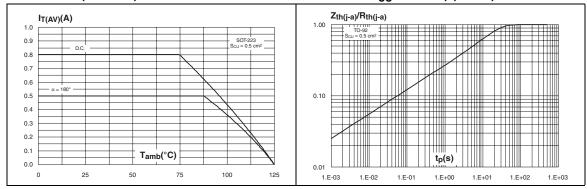


Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration (printed circuit board FR4, e<sub>CU</sub>=35 µm, S<sub>CU</sub>=0.5 cm<sup>2</sup>) (SOT-223)

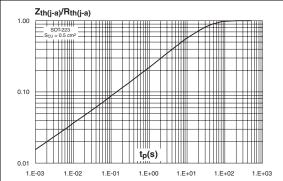
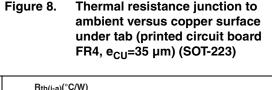
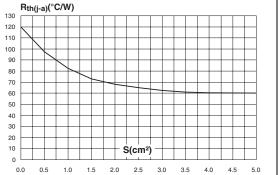
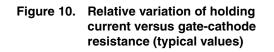
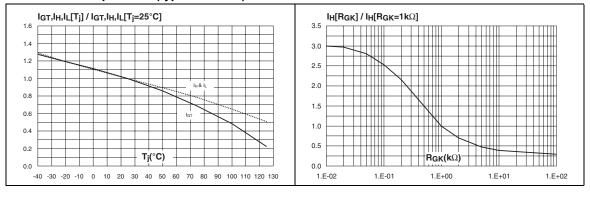


Figure 9. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)



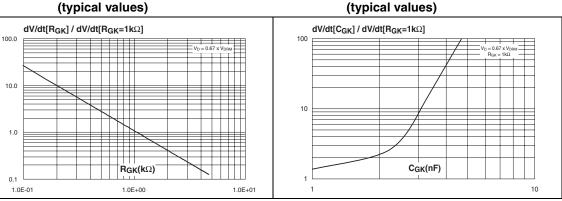


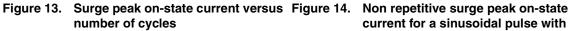




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#### Figure 11. Relative variation of dV/dt immunity Figure 12. Relative variation of dV/dt immunity versus gate-cathode resistance





current for a sinusoidal pulse with width t<sub>P</sub><10ms, and corresponding value of l<sup>2</sup>t

versus gate-cathode capacitance

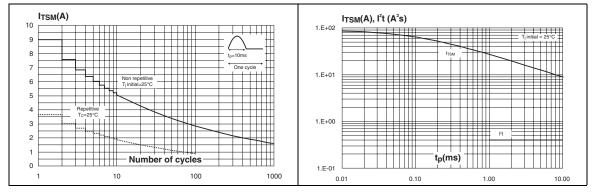
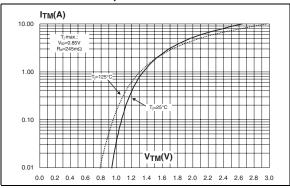
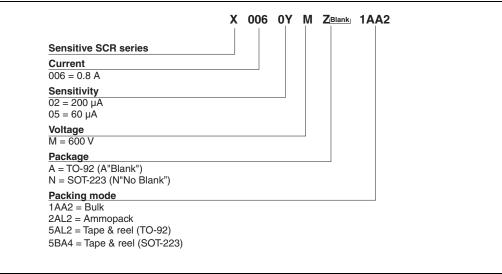


Figure 15. On-state characteristics (maximum values)



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# 2 Ordering information scheme





# 3 Package information

Table 4.	10-92	(plastic) uniterisions							
				DIMENSIONS					
		REF.	Millimeters		Inches				
	_			Min.	Тур.	Max.	Min.	Тур.	Max.
		А		1.35			0.053		
вÌсÌ		В			4.70			0.185	
↓ <u> </u>		С		2.54			0.100		
		D	4.40			0.173			
			Е	12.70			0.500		
			F			3.70			0.146
			а			0.50			0.019

## Table 4.TO-92 (plastic) dimensions

 Table 5.
 SOT-223 dimensions in mm

		DIMENSIONS					
	REF.	М	illimete	ers		Inches	
		Min.	Тур.	Max.	Min.	Тур.	Max.
	А			1.80			0.071
e1	A1		0.02			0.001	
D	В	0.60	0.70	0.80	0.024	0.027	0.031
	B1	2.90	3.00	3.10	0.114	0.118	0.122
	С	0.24	0.26	0.32	0.009	0.010	0.013
н Е	D	6.30	6.50	6.70	0.248	0.256	0.264
	е		2.3			0.090	
	e1		4.6			0.181	
e	E	3.30	3.50	3.70	0.130	0.138	0.146
	Н	6.70	7.00	7.30	0.264	0.276	0.287
	V			10°	max		

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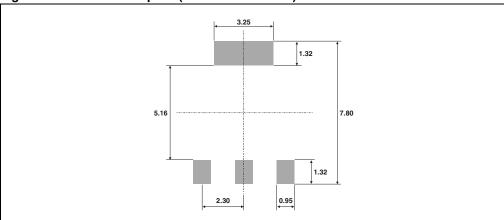


Figure 16. SOT-223 footprint (dimensions in mm)t

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



# 4 Ordering information

Ordering type	Voltage	Sensitivity	Marking	Package	Weight	Base qty	Delivery mode			
X00602MA 1AA2						2500	Bulk			
X00602MA 2AL2		200 µA	200 µA	200 4		X0602 MA	TO-92	0.2 g	2000	Ammopack
X00602MA 5AL2	600 V						2000			
X00602MN5BA4			X06 2M	SOT-223	0.12 g	1000	Tape & reel			
X00605MA 1AA2		60 µA	X0605 MA	TO-92	0.2 g	2500	Bulk			

# 5 Revision history

Date	Revision	Changes			
Jan-2002	3	Last update.			
08-Aug-2006	4	SOT-223 package added.			



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